LY8890

1.0 Watt Audio power Amplifier

FEATURES

- 2.5V~5.5V Power supply.
- Thermal shutdown Protection.
- Low current shutdown mode
- No capacitors and networks or bootstrap capacitors required
- Low noise during turn-on and turn-off transitions
- Lead free and green package available. (RoHS Compliant)
- Space Saving Package
 - 8-pin MSOP package.
 - 8-pin DFN Package

APPLICATION

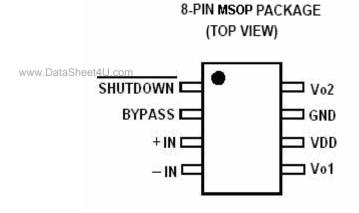
- Portable electronic devices
- Mobile Phones
- PDAs

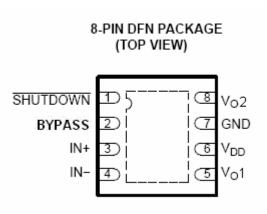
GENERAL DESCRIPTION

The LY8890 is a 1.0W audio power amplifier. It is capable of driving $8\,\Omega$ speaker load at a continuous average output of 1.0W/1% distortion (THD+N) from a 5.0V power supply. The LY8890 primarily designed for high quality application in other portable communication device. And the LY8890 audio amplifier features low power consumption shutdown mode. It is achieved by driving the shutdown pin with logic low. And the LY8890 has an internal thermal shutdown protection feature.

The LY8890 audio amplifier was designed specifically to provide high quality output power with a minimal amount of external components. The LY8890 does not require output capacitors, and the LY8890 is ideally suited for other low voltage applications or portable electronic devices where minimal power consumption is a primary requirement.

PIN CONFIGURATION





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PIN DESCRIPTION

SYMBOL	Pin No.		DESCRIPTION	
OTHER	MSOP	DFN	BECOKII HON	
SHUTDOWN	1	1	Shutdown the device.(when low level is active the pin)	
BYPASS	2	2	Bypass pin	
+IN	3	3	Positive Input	
-IN	4	4	Negative Input	
Vo1	5	5	Negative output	
V_{DD}	6	6	Power Supply	
GND	7	7	Ground	
Vo2	8	8	Positive Output	

APPLICATION CIRCUIT

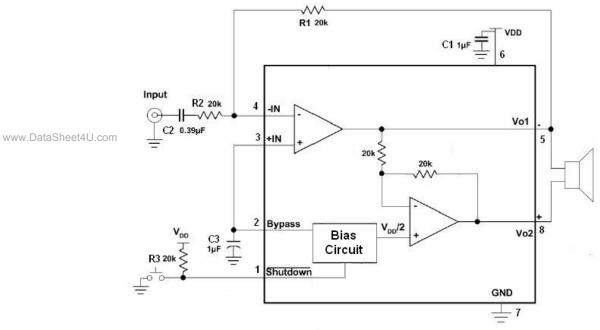


Figure 1. Audio Amplifier with Single -Ended Input

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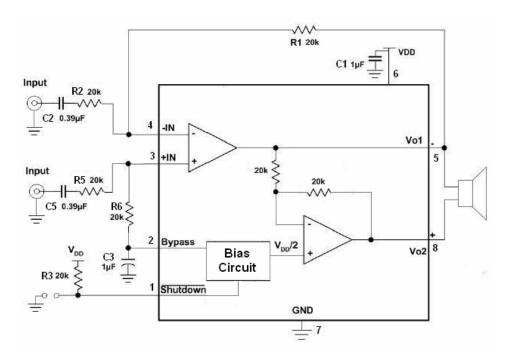


Figure 2. Audio Amplifier with Differential Input

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PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V _{DD}	6.0	V
Operating Temperature	TA	-40 to 85 (I grade)	${\mathbb C}$
Input Voltage	Vı	-0.3V to V _{DD} +0.3V	V
Storage Temperature	Тѕтс	-65 to 150	$^{\circ}$
Power Dissipation	PD	Internally Limited	W
ESD Susceptibility	VESD	2000	V
Junction Temperature	Тјмах	150	$^{\circ}$
Soldering Temperature (under 10 sec)	Tsolder	260	$^{\circ}$

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DC ELECTRICAL CHARACTERISTICS (VDD=5V, TA=25°C)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Power Supply Current	I _{DD}	V_{IN} = 0V, I_O = 0A, No Load	ı	4.0	10.0	mA
l ower Supply Current		V_{IN} = 0V, I_O = 0A, 8Ω Load	ı	5.0	15.0	mA
Shutdown Current	Isp	Vshutdown = 0V	-	0.1	2.0	μA
Shutdown Voltage Input High	Vsdih		1.2	-	-	V
Shutdown Voltage Input Low	Vsdil		-	-	0.4	V
Output Offset Voltage	Vos		-	7.0	50.0	mV
Resistor Output to GND	Rout-gnd		7.0	8.5	9.7	kΩ
Output Power (8Ω)	Po	THD = 2% (max), f = 1 kHz	-	1.0		W
Total Harmonic Distortion+ Noise	THD+N	Po = 0.4 Wrms; f = 1kHz	ı	0.2		%
Power Supply Rejection Ratio	PSRR	Vripple = 200mV sine p-p Input terminated with 10Ω to GND	ı	57 (f = 217Hz) 66 (f = 1kHz)	ı	dB
	Twu	Bypass pin Cap. = 0.22 uF	ı	168	1	ms
Wake-up time		Bypass pin Cap. = 0.33 uF	1	224	1	ms
wake-up time		Bypass pin Cap. = 0.47 uF	1	326	1	ms
		Bypass pin Cap. = 1.0 uF	1	524	1	ms
Thermal Shutdown Temperature	T _{SD}		150	170	190	$^{\circ}$ C
Shut Down Time	TSDT	8 Ω load		1.0		ms

DC ELECTRICAL CHARACTERISTICS (VDD=3V, TA=25°C)

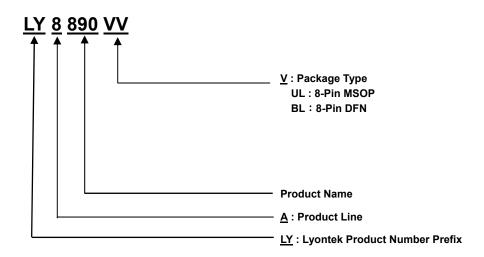
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Power Supply Current	IDD	V_{IN} = 0V, I_O = 0A, No Load	ı	3.5	9.0	mA
Fawer Supply Current		V_{IN} = 0V, I_O = 0A, 8Ω Load	-	4.5	14.0	mA
Shutdown Current	Isp	Vshutdown = 0V	-	0.1	2.0	μA
Shutdown Voltage Input High	Vsdih		1.2	-	-	V
Shutdown Voltage Input Low	Vsdil		ı	-	0.4	V
Output Offset Voltage	Vos		ı	7.0	50.0	mV
Resistor Output to GND	ROUT-GND		7.0	8.5	9.7	$\mathbf{k}\Omega$
Output Power (8Ω)	Po	THD = 1% (max), f = 1 kHz	0.28	0.31		W
Total Harmonic Distortion+ Noise	THD+N	Po = 0.15 Wrms, f = 1 kHz	•	0.1	-	%
Power Supply Rejection Ratio	LPSKK	V_{ripple} = 200mV sine p-p Input terminated with 10 Ω to GND	ı	57 (f = 217Hz) 65 (f = 1kHz)	ı	dB
	Twu	Bypass pin Cap. = 0.22 uF	ı	101	ı	ms
Wake-up time		Bypass pin Cap. = 0.33 uF	1	140	-	ms
value up time		Bypass pin Cap. = 0.47 uF	ı	207	-	ms
		Bypass pin Cap. = 1.0 uF	-	376	-	ms
Thermal Shutdown Temperature	Tsp		150	170	190	$^{\circ}\mathbb{C}$

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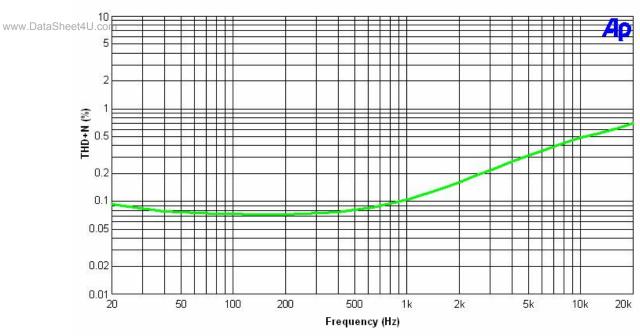
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ORDERING INFORMATION



TYPICAL PERFORMANCE CHARACTERISTICS

Figure 3 THD+N vs Frequency at VDD=5V, RL= 8Ω , PWR=250mW, Av=2



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Figure 4 THD+N vs Frequency at VDD=3.3V, RL= 8Ω , PWR=250mW, Av=2

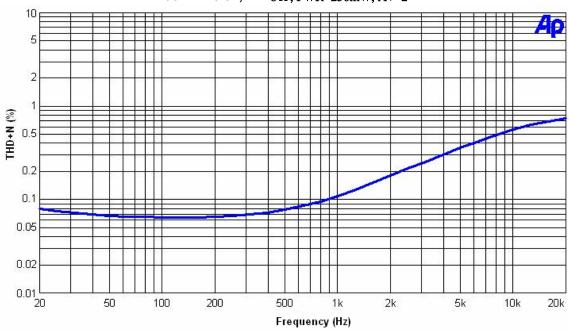
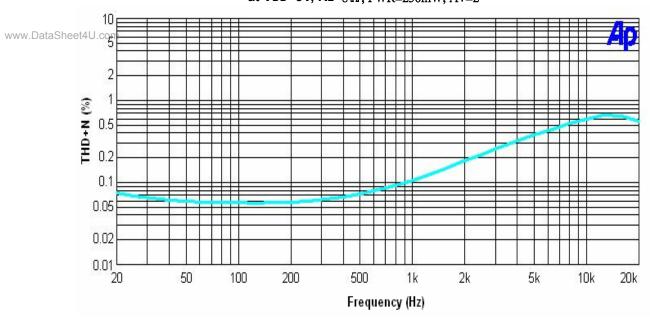


Figure 5
THD+N vs Frequency
at VDD=3V, RL=8Ω, PWR=250mW, Av=2



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Figure 6 THD+N vs Frequency at VDD=2.6V, RL= 8Ω , PWR=250mW, Av=2

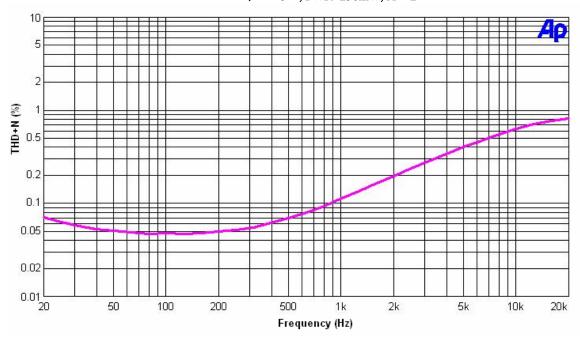
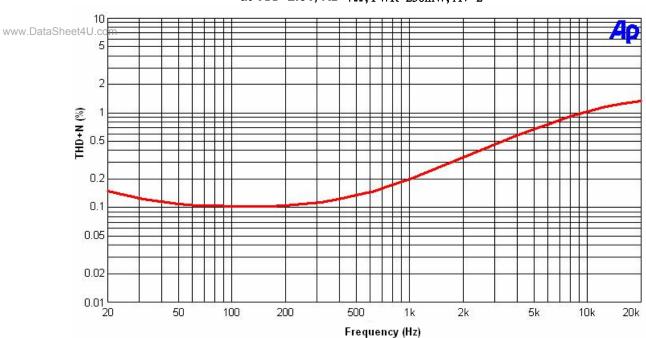


Figure 7 THD+N vs Frequency at VDD=2.6V, RL= 4Ω , PWR=250mW, Av=2



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Figure 8 THD+N vs Power Out @ VDD=5V, RL=8Ω, f=1kHz, Av=2

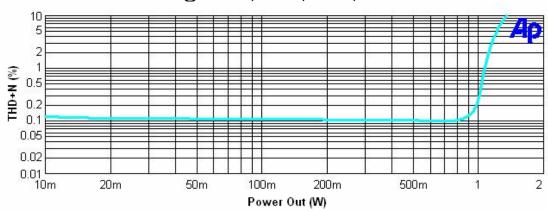


Figure 9 THD+N vs Power Out @ VDD=3.3V, RL=8Ω, f=1kHz, Av=2

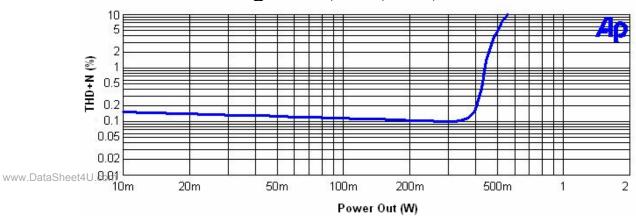
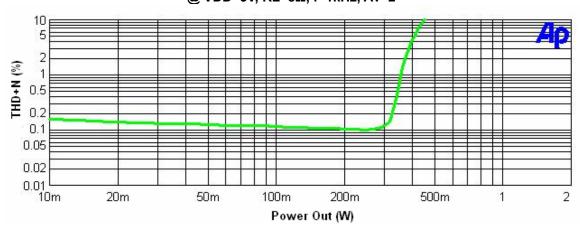


Figure 10 THD+N vs Power Out @ VDD=3V, RL=8Ω, f=1kHz, Av=2



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Figure 11
THD+N vs Power Out
@ VDD=2.6V, RL=8Ω, f=1kHz, Av=2

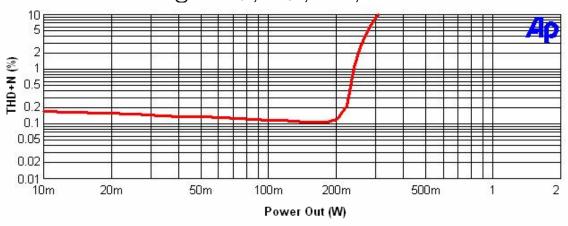
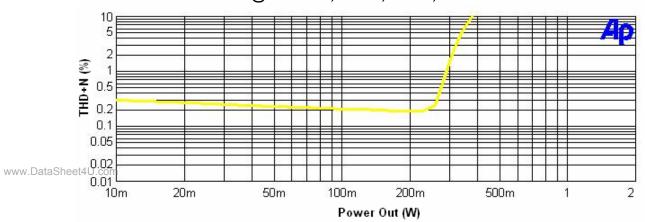


Figure 12 THD+N vs Power Out @ VDD=2.6V, RL=4Ω, f=1kHz, Av=2



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Figure 13
Power Supply Rejection Ratio (PSRR) @ Av=2
VDD=5V, V ripple =200mvp-p, RL=8Ω, RIN=Float

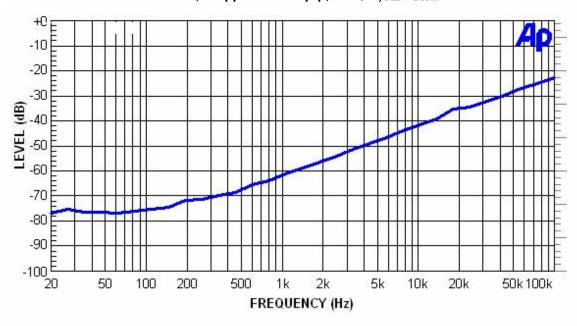
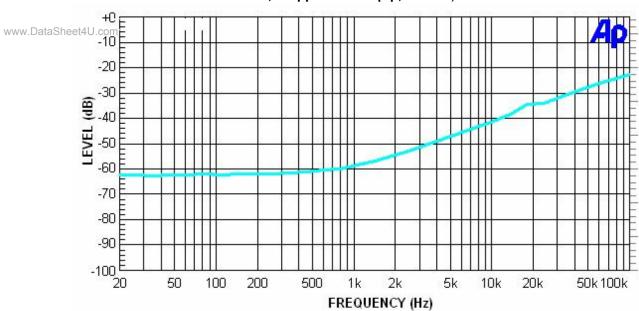


Figure 14
Power Supply Rejection Ratio (PSRR) @ Av=2
VDD=3V, V ripple =200mvp-p, RL= 8Ω , RIN=Float



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Figure 15
Power Supply Rejection Ratio (PSRR) @ Av=4
VDD=5V, V ripple =200mvp-p, RL=8Ω, RIN=Float

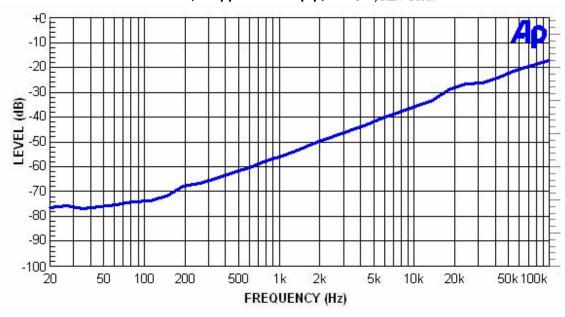
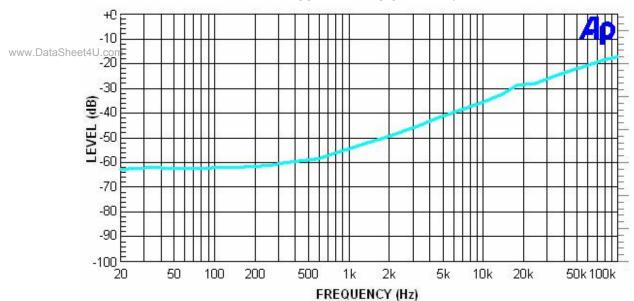


Figure 16
Power Supply Rejection Ratio (PSRR) @ Av=4
VDD=3V, V ripple =200mvp-p, RL=8Ω, RIN=Float



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Figure 17
Power Supply Rejection Ratio (PSRR) @ Av=2
VDD=5V, V ripple =200mvp-p, RL= 8Ω , RIN= 10Ω

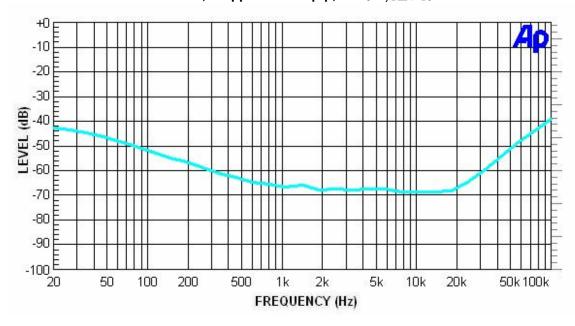
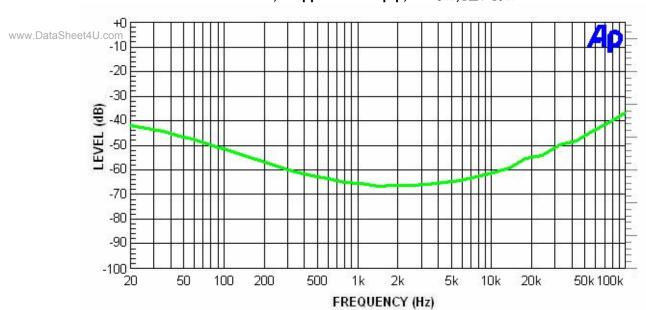


Figure 18 Power Supply Rejection Ratio (PSRR) @ Av=2 VDD=3V, V ripple =200mvp-p, RL= 8Ω , RIN= 10Ω



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Figure 19
Power Supply Rejection Ratio (PSRR) @ Av=2
VDD=3.3V, V ripple =200mvp-p, RL= 8Ω , RIN= 10Ω

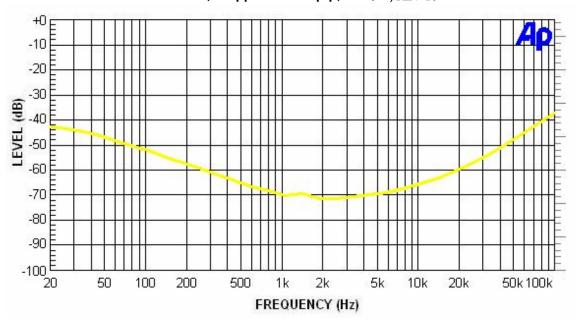
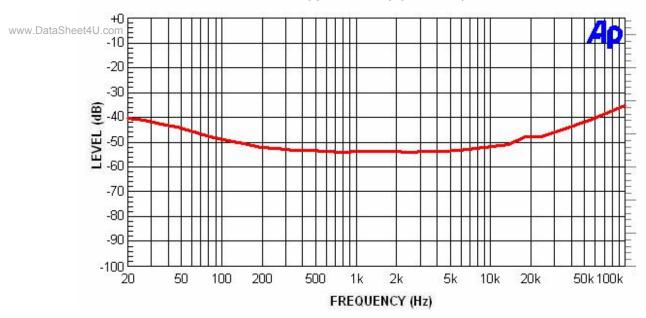


Figure 20 Power Supply Rejection Ratio (PSRR) @ Av=2 VDD=2.6V, V ripple =200mvp-p, RL= 8Ω , RIN= 10Ω



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Figure 21
Power Supply Rejection Ratio (PSRR) @ Av=4
VDD=5V, V ripple =200mvp-p, RL= 8Ω , RIN= 10Ω

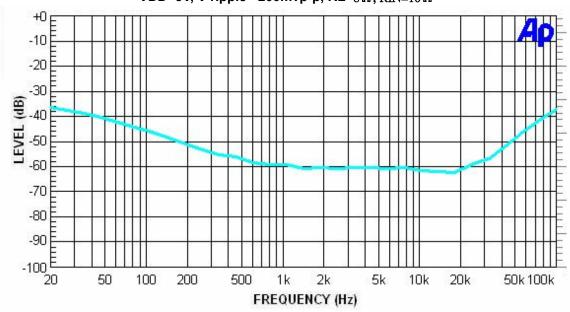
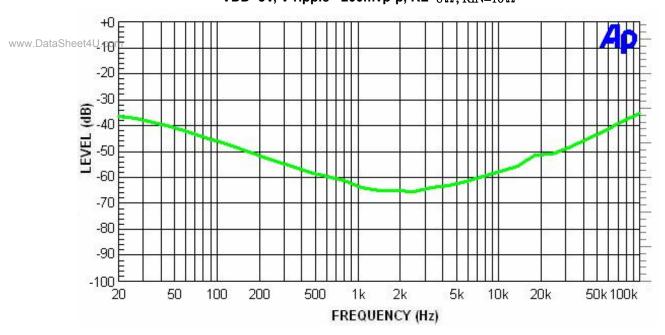


Figure 22 Power Supply Rejection Ratio (PSRR) @ Av=4 VDD=3V, V ripple =200mvp-p, RL= 8Ω , RIN= 10Ω



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APPLICATION INFORMATION

BRIDGED CONFIGURATION EXPLANATION

As shown in Figure 1, the LY8890 has two operational amplifiers internally, allowing for a few different amplifier configurations. The first amplifier's gain is externally configurable, while the second amplifier is internally fixed in a unity-gain, inverting configuration. The closed-loop gain of the first amplifier is set by selecting the ratio of Rf to RIN while the second amplifier's gain is fixed by the two internal $20k\Omega$ resistors. Figure 1 shows that the output of amplifier one serves as the input to amplifier two which results in both amplifiers producing signals identical in magnitude, but out of phase by 180° . Consequently, the differential gain for the IC is

$$AVD= 2 X (R_f/R_{IN})$$

By driving the load differentially through outputs Vo1 and Vo2, an amplifier configuration commonly referred to as "bridged mode" is established. Bridged mode operation is different from the classical single-ended amplifier configuration where one side of the load is connected to ground.

A bridge amplifier design has a few distinct advantages over the single-ended configuration, as it provides differential drive to the load, thus doubling output swing for a specified supply voltage. Four times the output power is possible as compared to a single-ended amplifier under the same conditions.

This increase in attainable output power assumes that the amplifier is not current limited or clipped. In order to choose an amplifier's closed-loop gain without causing excessive clipping, please refer to the Audio Power Amplifier Design section.

A bridge configuration, such as the one used in the LY8890, also creates a second advantage over single -ended amplifiers. Since the differential outputs, Vo1 and Vo2, are biased at half-supply, no net DC voltage exists across the load. This eliminates the need for an output coupling capacitor which is required in a single supply, single-ended amplifier configuration. Without an output coupling capacitor, the half-supply bias across the load would result in both increased internal IC power dissipation and also possible loudspeaker damage.

Power Dissipation

Power dissipation is a major concern when designing a successful amplifier, whether the amplifier is bridged or single-ended. A direct consequence of the increased power delivered to the load by a bridge amplifier is an increase in internal power dissipation. Since the LY8890 has two operational amplifiers in one package, the maximum internal power dissipation is 4 times that of a single-ended amplifier. The maximum power dissipation for a given application can be derived from the power dissipation graphs of from equation 1.

$$P_{DMAX} = 4 X (V_{DD})^2 / (2 \pi^2 R_L) \dots (1)$$

It is critical that the maximum junction temperature TJMAX of 150° C is not exceeded. TJMAX can be determine from the power derating curves by using P_{DMAX} and the PC board foil area. By adding additional copper foil, the thermal resistance of the application can be reduced, resulting in higher P_{DMAX} . Additional copper foil can be added to any of the leads connected to the LY8890.If TJMAX still exceeds 150° C, then additional changes must be made. These changes can include reduced supply voltage, higher load impedance, or reduced ambient temperature. Internal power dissipation is a function of output power.

POWER SUPPLY BYPASSING

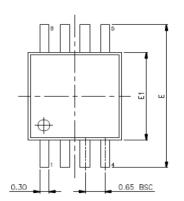
As with any amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection. The capacitor location on both the bypass and power supply pins should be as close to the device as possible.

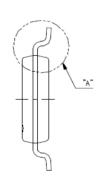
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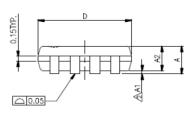
1.0 Watt Audio power Amplifier

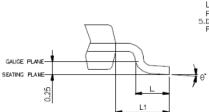
PACKAGE OUTLINE DIMENSION

8 pin 25.6 mil MSOP Package Outline Dimension









SYMBOLS	MIN.	NOM.	MAX.
Α	-	_	1.10
A1	0.00	_	0.15
A2	0.75	0.85	0.95
D	3.00 BSC		
E	4.90 BSC		
E1	3.00 BSC		
L	0.40	0.60	0.80
L1	0.95 REF		
θ*		_	8

UNIT : MM

NOTES:

1.JEDEC OUTLINE: MO-187 AA

2.DIMENSION 'D' DOES NOT INCLUDE MOLD FLASH,
PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS
OR CATE BURRS SHALL NOT EXCEED 0.15 PER SIDE.

3.DIMENSION 'E1' DOES NOT INCLUDE INTERLEAD FLASH OR
PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL
NOT EXCEED 0.25 PER SIDE.

4.DIMENSION '0.22' DOES NOT INCLUDE DAMBAR PROTRUSION.
ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 MM
TOTAL IN EXCESS OF THE '0.22' DIMENSION AT MAXIMUM
MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE
LOWER RADIUS OF THE FOOT. MINIMUM SPACE BETWEEN
PROTRUSION AND ADJACENT LEAD IS 0.07 MM.

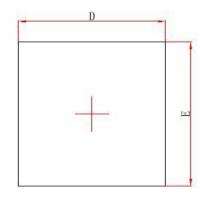
5.DIMENSIONS 'D' AND 'E1' TO BE DETERMINED AT DATUN
PLANE ...

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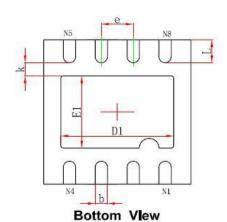
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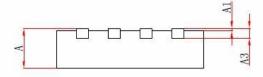
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8 Pin DFN Package Outline Dimension



Top Vlew





Side View

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Campbol	Dimensions In Millimeters			
Symbol	Min.	Max.		
Α	0.700/0.800	0.800/0.900		
A1	0.000	0.050		
A3	0.203	REF.		
D	2.900	3.100		
E	2.900	3.100		
D1	2.200	2.400		
E1	1.400	1.600		
k	0.200MIN.			
b	0.180	0.300		
е	0.650TYP.			
L	0.375	0.575		

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